NSN 5961-01-299-8455



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-299-8455 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage/static/emitter open and -100.0 collector-to-emitter substaining voltage, with voltage between base and emitter and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -2.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 5.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

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